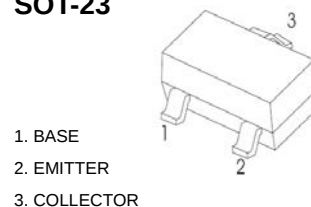


TRANSISTOR (NPN)

FEATURES

- Audio power amplifier application
- High h_{FE} : $h_{FE}=100\sim320$
- Complementary to 2SA1981

SOT-23



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	35	V
V_{CEO}	Collector-Emitter Voltage	30	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	800	mA
P_C	Collector Power Dissipation	200	mW
T_J, T_{STG}	Operation Junction and Storage Temperature Range	-55-150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 0.1\text{mA}, I_B=0$	35			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}, I_B=0$	30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 0.01\text{mA}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=35\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}= 5\text{V}, I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=1\text{V}, I_C= 100\text{mA}$	100		320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C= 500\text{mA}, I_B=50\text{mA}$			0.5	V
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=10\text{mA}$		120		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E= 0, f=1\text{MHz}$		13		pF

CLASSIFICATION OF $h_{FE(1)}$

Rank	O	Y
Range	100-200	160-320
Marking	FAO	FAY

Typical Characteristics

